



# 1H1G THRU 1H8G

## GLASS PASSIVATED HIGH EFFICIENCY RECTIFIERS

Reverse Voltage - 50 to 1000 Volts    Forward Current - 1.0 Ampere

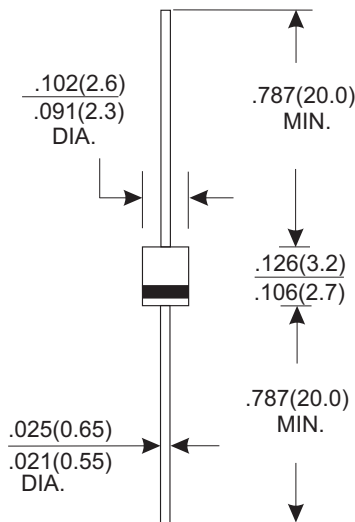
### FEATURES

- \* Low forward voltage drop
- \* High current capability
- \* High reliability
- \* High surge current capability

### MECHANICAL DATA

- \* Case: Molded plastic
- \* Epoxy: UL 94V-0 rate flame retardant
- \* Lead: Axial leads, solderable per MIL-STD-202, method 208 guaranteed
- \* Polarity: Color band denotes cathode end
- \* Mounting position: Any
- \* Weight: 0.19 grams

R-1



Dimensions in inches and (millimeters)

## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating 25°C ambient temperature unless otherwise specified.  
 Single phase half wave, 60Hz, resistive or inductive load.  
 For capacitive load, derate current by 20%.

TYPE NUMBER	1H1G	1H2G	1H3G	1H4G	1H5G	1H6G	1H7G	1H8G	UNITS
Maximum Recurrent Peak Reverse Voltage	50	100	200	300	400	600	800	1000	V
Maximum RMS Voltage	35	70	140	210	280	420	560	700	V
Maximum DC Blocking Voltage	50	100	200	300	400	600	800	1000	V
Maximum Average Forward Rectified Current .375"(9.5mm) Lead Length at Ta=55°C	1.0								A
Peak Forward Surge Current, 8.3 ms single half sine-wave superimposed on rated load (JEDEC method)	30								A
Maximum Instantaneous Forward Voltage at 1.0A	1.0				1.3	1.85			V
Maximum DC Reverse Current Ta=25°C	5.0								µA
at Rated DC Blocking Voltage Ta=100°C	100								µA
Maximum Reverse Recovery Time (Note 1)	50				70				nS
Typical Junction Capacitance (Note 2)	20				15				pF
Operating Temperature Range Tj	-65 — +150								°C
Storage Temperature Range Tstg	-65 — +150								°C
Marking Code	E1	E2	E3	E4	E5	E6	E7	E8	

**NOTES:**

1. Reverse Recovery Time test condition: IF=0.5A, IR=1.0A, IRR=0.25A
2. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

# RATING AND CHARACTERISTIC CURVES (1H1G THRU 1H8G)

FIG.1-TYPICAL FORWARD CHARACTERISTICS

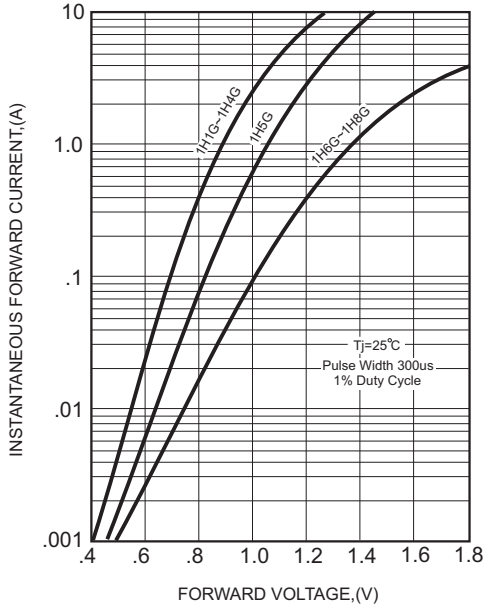


FIG.2-TYPICAL FORWARD CURRENT DERATING CURVE

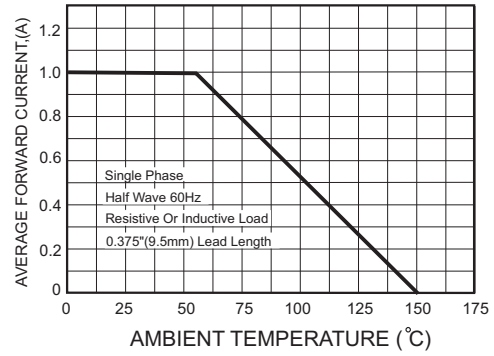


FIG.4-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

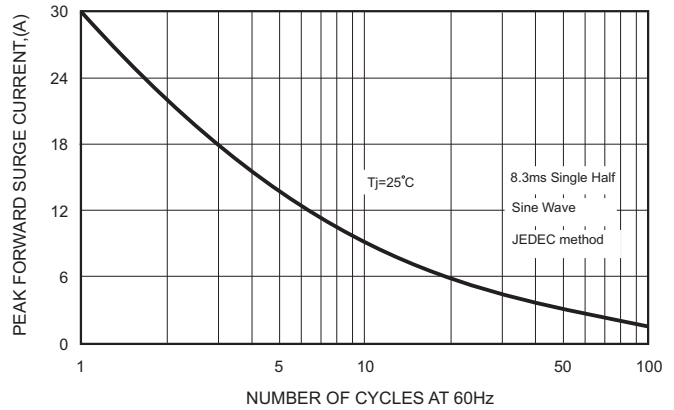
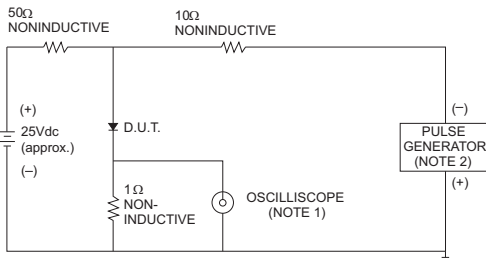


FIG.3- TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTICS



NOTES: 1. Rise Time= 7ns max., Input Impedance= 1 megohm, 22pF.  
2. Rise Time= 10ns max., Source Impedance= 50 ohms.

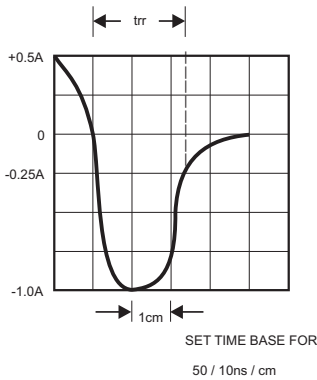


FIG.5-TYPICAL JUNCTION CAPACITANCE

